# **Octal 3-State Noninverting Bus Transceiver**

## High-Performance Silicon-Gate CMOS

The 74HC245 is identical in pinout to the LS245. The device inputs are compatible with standard CMOS outputs; with pull-up resistors, they are compatible with LSTTL outputs.

The HC245 is a 3-state noninverting transceiver that is used for 2-way asynchronous communication between data buses. The device has an active-low Output Enable pin, which is used to place the I/O ports into high-impedance states. The Direction control determines whether data flows from A to B or from B to A.

### Features

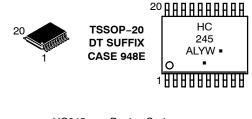
- Output Drive Capability: 15 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1.0 µA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- ESD Performance: HBM > 2000 V; Machine Model > 200 V
- Chip Complexity: 308 FETs or 77 Equivalent Gates
- This is a Pb–Free Device



### **ON Semiconductor®**

http://onsemi.com

MARKING DIAGRAMS

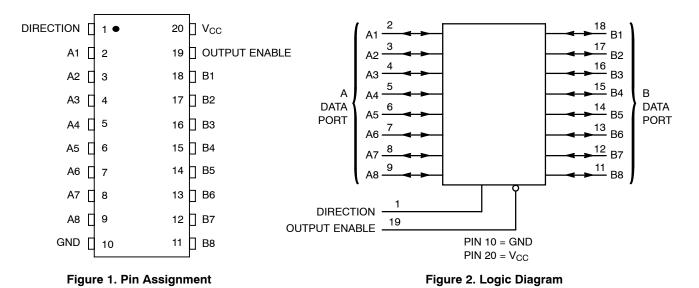


HC245= Device CodeA= Assembly LocationL= Wafer LotY= YearW= Work Week•= Pb-Free Package

(Note: Microdot may be in either location)

### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.



### **FUNCTION TABLE**

Contro	l Inputs	
Output Enable	Direction	Operation
L	L	Data Transmitted from Bus B to Bus A
L	Н	Data Transmitted from Bus A to Bus B
Н	Х	Buses Isolated (High-Impedance State)
X = don't car	e	

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
74HC245DTR2G	TSSOP-20*	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. \*This package is inherently Pb-Free.

### MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage	$-0.5$ to V_{CC}+0.5	V
V <sub>OUT</sub>	DC Output Voltage (Note 2)	$-0.5$ to $V_{CC}$ $+0.5$	V
I <sub>IK</sub>	DC Input Diode Current	±20	mA
I <sub>OK</sub>	DC Output Diode Current	±35	mA
I <sub>OUT</sub>	DC Output Sink Current	±35	mA
I <sub>CC</sub>	DC Supply Current per Supply Pin	±75	mA
I <sub>GND</sub>	DC Ground Current per Ground Pin	±75	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
TJ	Junction Temperature Under Bias	+ 150	°C
$\theta_{JA}$	Thermal Resistance TSSOP	128	°C/W
PD	Power Dissipation in Still Air at 85°C TSSOP	450	mW
MSL	Moisture Sensitivity	Level 1	
F <sub>R</sub>	Flammability Rating Oxygen Index: 30% to 35%	UL 94 V-0 @ 0.125 in	
$V_{\text{ESD}}$	ESD Withstand Voltage Human Body Model (Note 3) Machine Model (Note 4)	> 2000 > 200	V
I <sub>LATCHUP</sub>	Latchup Performance Above V <sub>CC</sub> and Below GND at 85°C (Note 5)	±300	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 20 ounce copper trace with no air flow.

I<sub>O</sub> absolute maximum rating must observed.
 Tested to EIA/JESD22-A114-A.

4. Tested to EIA/JESD22-A115-A.

5. Tested to EIA/JESD78.

### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)		2.0	6.0	V
V <sub>in</sub> , V <sub>out</sub>	DC Input Voltage, Output Voltage (Referenced to GND)		0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature, All Package Types		-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time $V_{CC} = $ (Figure 3) $V_{CC} = $ $V_{CC} = $	4.5 V	0 0 0	1000 500 400	ns

				Guaranteed Limit			
Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	–55 to 25°C	≤ 85°C	≤ 125°C	Unit
V <sub>IH</sub>	Minimum High-Level Input Voltage	$\begin{array}{l} V_{out} = V_{CC} - 0.1 \text{ V} \\  I_{out}  \leq 20 \ \mu\text{A} \end{array}$	2.0 3.0 4.5 6.0	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	V
V <sub>IL</sub>	Maximum Low-Level Input Voltage	$\begin{array}{l}  V_{out} = 0.1 \text{ V} \\  I_{out}  \leq 20  \mu\text{A} \end{array}$	2.0 3.0 4.5 6.0	0.5 0.9 1.35 1.8	0.5 0.9 1.35 1.8	0.5 0.9 1.35 1.8	V
V <sub>OH</sub>	Minimum High–Level Output Voltage	$ \begin{aligned} V_{in} &= V_{IH} \\  I_{out}  &\leq 20 \; \mu A \end{aligned} $	2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V
			3.0 4.5 6.0	2.48 3.98 5.48	2.34 3.84 5.34	2.2 3.7 5.2	
V <sub>OL</sub>	Maximum Low-Level Output Voltage		2.0 4.5 6.0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V
			3.0 4.5 6.0	0.26 0.26 0.26	0.33 0.33 0.33	0.4 0.4 0.4	
l <sub>in</sub>	Maximum Input Leakage Current	V <sub>in</sub> = V <sub>CC</sub> or GND	6.0	±0.1	±1.0	±1.0	μA
I <sub>OZ</sub>	Maximum Three-State Leakage Current	$\begin{array}{l} \text{Output in High-Impedance State} \\ \text{V}_{in} = \text{V}_{IL} \text{ or V}_{IH} \\ \text{V}_{out} = \text{V}_{CC} \text{ or GND} \end{array}$	6.0	±0.5	±5.0	±10	μA
I <sub>CC</sub>	Maximum Quiescent Supply Current (per Package)	$V_{in} = V_{CC} \text{ or GND}$ $I_{out} = 0 \ \mu A$	6.0	4.0	40	40	μA

### DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

6. Information on typical parametric values and high frequency or heavy load considerations can be found in the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

### **AC ELECTRICAL CHARACTERISTICS** ( $C_L = 50 \text{ pF}$ , Input $t_r = t_f = 6 \text{ ns}$ )

			Guaranteed Limit			
Symbol	Parameter	V <sub>CC</sub> V	–55 to 25°C	≤ <b>85</b> °C	≤ 125°C	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, A to B, B to A (Figures 1 and 3)	2.0 3.0 4.5 6.0	75 55 15 13	95 70 19 16	110 80 22 19	ns
t <sub>PLZ</sub> , t <sub>PHZ</sub>	Maximum Propagation Delay, Direction or Output Enable to A or B (Figures 2 and 4)	2.0 3.0 4.5 6.0	110 90 22 19	140 110 28 24	165 130 33 28	ns
t <sub>PZL</sub> , t <sub>PZH</sub>	Maximum Propagation Delay, Output Enable to A or B (Figures 2 and 4)	2.0 3.0 4.5 6.0	110 90 22 19	140 110 28 24	165 130 33 28	ns
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output Transition Time, Any Output (Figures 1 and 3)	2.0 3.0 4.5 6.0	60 23 12 10	75 27 15 13	90 32 18 15	ns
C <sub>in</sub>	Maximum Input Capacitance (Pin 1 or Pin 19)	-	10	10	10	pF
C <sub>out</sub>	Maximum Three-State I/O Capacitance (I/O in High-Impedance State)	-	15	15	15	pF

7. For propagation delays with loads other than 50 pF, and information on typical parametric values, see the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

		Typical @ 25°C, V <sub>CC</sub> = 5.0 V	
C <sub>PD</sub>	Power Dissipation Capacitance (Per Transceiver Channel) (Note 8)	40	рF

8. Used to determine the no-load dynamic power consumption:  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ . For load considerations, see the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

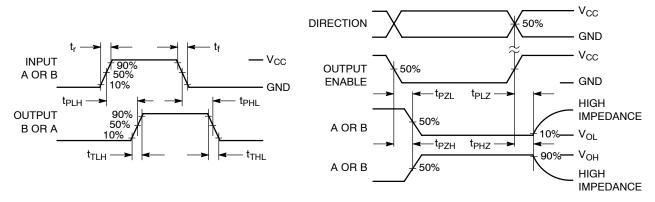
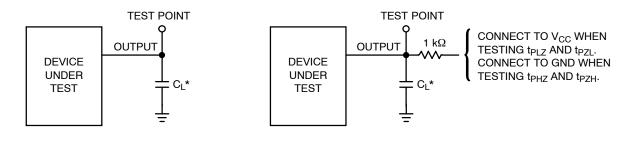


Figure 3. Switching Waveform

Figure 4. Switching Waveform



\*Includes all probe and jig capacitance

\*Includes all probe and jig capacitance

Figure 5. Test Circuit

Figure 6. Test Circuit

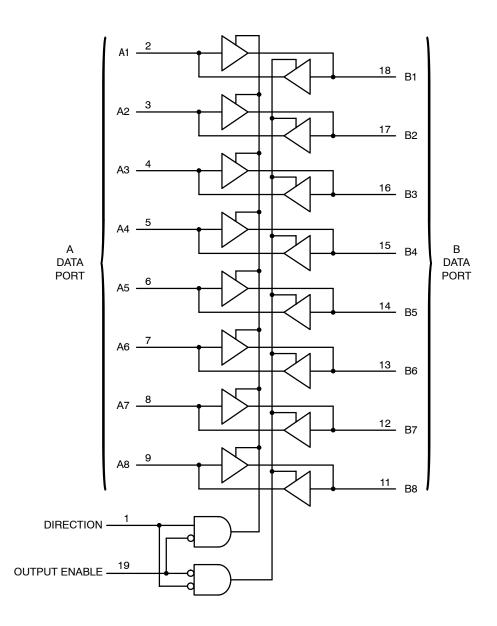
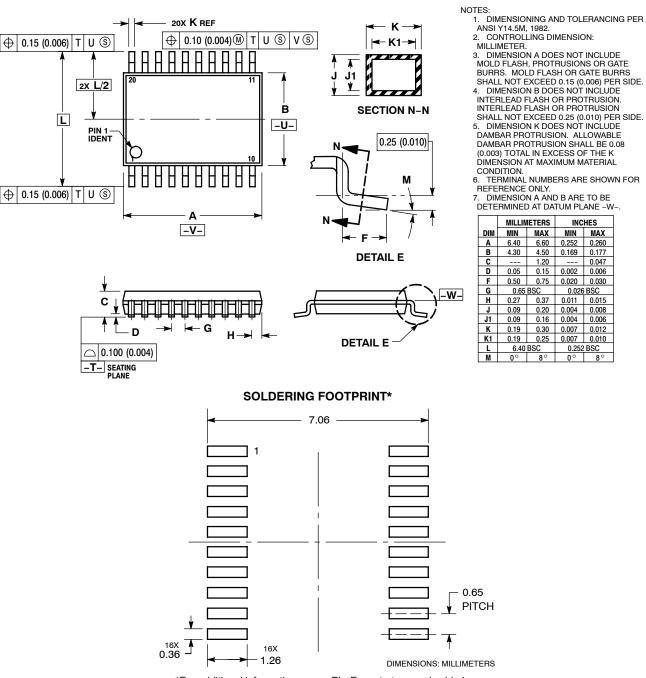


Figure 7. Expanded Logic Diagram

### PACKAGE DIMENSIONS

TSSOP-20 CASE 948E-02 ISSUE C



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PITCH

MILLIMETERS

6.40

4.30

0.05

6.40 BSC

0°

MIN MAX

INCHES

MIN MAX

0.252 BSC

0° 80

6.60 0.252 0.260

4.50 0.169 0.177

 1.20
 -- 0.047

 0.15
 0.002
 0.006

0.50 0.75 0.020 0.030

0.65 BSC 0.026 BSC 0.27 0.37 0.011 0.015

0.09 0.20 0.004 0.008 0.09 0.16 0.004 0.006

 0.19
 0.30
 0.007
 0.012

 0.19
 0.25
 0.007
 0.010

8°

ON Semiconductor and I are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability, arising out of the application or use of any provided in SCILLC data sheets and/or specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other application in which the Failure of the SCILLC product create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use copyright laws and is not for resale in any manner.

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5773–3850 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative